

CTM452, CTM453

5 Pin Mini-Flat DMC-Isolator®

1 Mbit/s High Speed Transistor Coupler

Features

- High speed: 1 Mbit/s
- High isolation voltage between input and output (Viso=3750 Vrms)
- Guaranteed performance from 0°C to 70°C
- **RoHS and REACH compliance**
- Halogen Free compliance
- MSL class 1
- **Regulatory Approvals**
 - ✓ UL - UL1577 (E364000)
 - VDE EN60747-5-5(VDE0884-5) 1
 - √ CQC - GB4943.1, 2022 (14001105803)
 - IEC62368 (FI/41119)

Description

The CTM452 and CTM453 devices each consist of an infrared emitting diode, optically coupled to a high speed photo detector transistor.

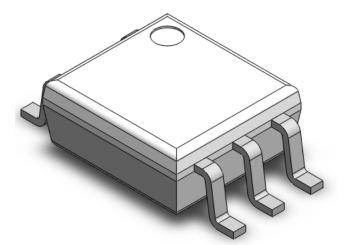
A separate connection for the photodiode bias and Wide operating temperature range of -55°C to 125°C output-transistor collector increase the speed by several orders of magnitude over conventional phototransistor couplers by reducing the base-collector capacitance of the input transistor. The devices are packaged in a Mini-Flat package.

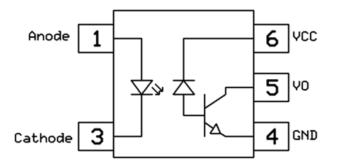
Applications

- Line receivers
- **Telecommunication equipment**
- Feedback loop in switch-mode power supplies •
- Home appliances
- High speed logic ground isolation

Package Outline

Schematic







Absolute Maximum Ratings $T_A = 25^{\circ}C$, unless otherwise specified

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameters	Ratings	Units	Notes
Viso	Isolation voltage (AC, 1 minute, 40 ~ 60% R.H.)	3750	VRMS	
Topr	Operating temperature	-55 ~ +125	°C	
Tstg	Storage temperature	-55 ~ +150	°C	
Tsol	Soldering temperature (For 10 seconds)	260	°C	
Emitter				
lF	Forward current	25	mA	
I _{FP}	Peak forward current (50% duty, 1ms P.W)	50	mA	
F(TRANS)	Peak transient current (≤1µs P.W,300pps)	1	А	
VR	Reverse voltage	5	V	
PD	Power dissipation	45	mW	
Detector		·		
PD	Power dissipation	100	mW	
I _{O(AVG)}	Average Output current	8	mA	
IO (Peak)	Peak Output current	16	mA	
Vo	Output voltage	-0.5 to 20	V	
Vcc	Supply voltage	-0.5 to 30	V	



Electrical Characteristics $T_A = 0 - 70^{\circ}C$ (unless otherwise specified). Typical values are measured at $T_A = 25^{\circ}C$ and $V_{cc} = 5V$

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	IF = 16mA	-	1.6	1.8	V	
VR	Reverse Voltage	IR = 10µA	5.0	-	-	V	
Δν _γ /Δτ _α	Temperature coefficient of forward voltage	IF =16mA	-	-1.6	-	mV/°C	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
		IF=0mA, Vo=Vcc=5.5V,		0.001	0.5		
		T _A =25°C	-	0.001			
		IF=0mA, Vo=Vcc=3.3V,		0.001	0.4		
Іон	Logic High Output Current	T _A =25°C	0.001 0	0.4	μA		
	lf	IF=0mA, Vo=Vcc=15V,		0.01	1		
		T _A =25°C	-	0.01	Ι		
		IF=0mA, Vo=Vcc=15V	-	-	50		
loo	Legis Lew Supply Support	I⊧=16mA, V₀=Open,		120	200	μΑ	
lcc∟	Logic Low Supply Current	Vcc=15V	-				
		$I_F=0mA$, $V_O=Open$, $V_{CC}=15V$,		- 0.01	1		
la au	Logia High Supply Current	T _A =25°C	-				
Іссн	Logic High Supply Current IF=0mA, VO=Open,	IF=0mA, VO=Open,			2	- μΑ	
		Vcc =15V	-				



Electrical Characteristics $T_A = 0 - 70^{\circ}$ C (unless otherwise specified). Typical values are measured at $T_A = 25^{\circ}$ C and $V_{cc} = 5V$

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes	
		I _F =16mA, V _O =0.4V,	20	00	50			
		V _{CC} =4.5V, T _A =25°C	20	-	50			
		I _F =16mA, V _O =0.5V,	15			1		
стр	Current Transfer Datio	Vcc=4.5V	15	-	-	%		
CTR	Current Transfer Ratio	I⊧=16mA, V₀=0.4V,	4.0	10	54	%		
		V _{CC} =3.3V, T _A =25°C	18	51				
		I⊧=16mA, V₀=0.5V,						
		Vcc=3.3V	13	13				
		I_{F} =16mA, I_{O} =3mA, V_{CC} =4.5V,			0.4			
		T _A =25°C		0.4				
		IF=16mA, Io=3mA, Vcc=3.3V,				0.4		
Mai	Logic Low Output Voltage	T _A =25°C		0.4	V			
Vol	Logic Low Output voltage	I⊧=16mA, I₀=2.4mA,			-	- 0.5	v	
		Vcc=4.5V	-	-	0.5	-		
		I _F =16mA, I _O =2.4mA,			0.5			
		V _{CC} =3.3V						

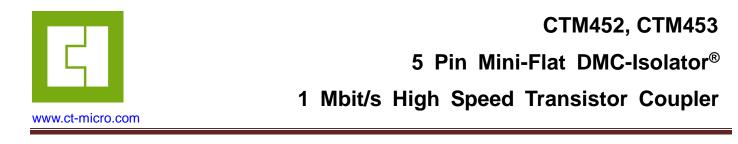
Transfer Characteristics



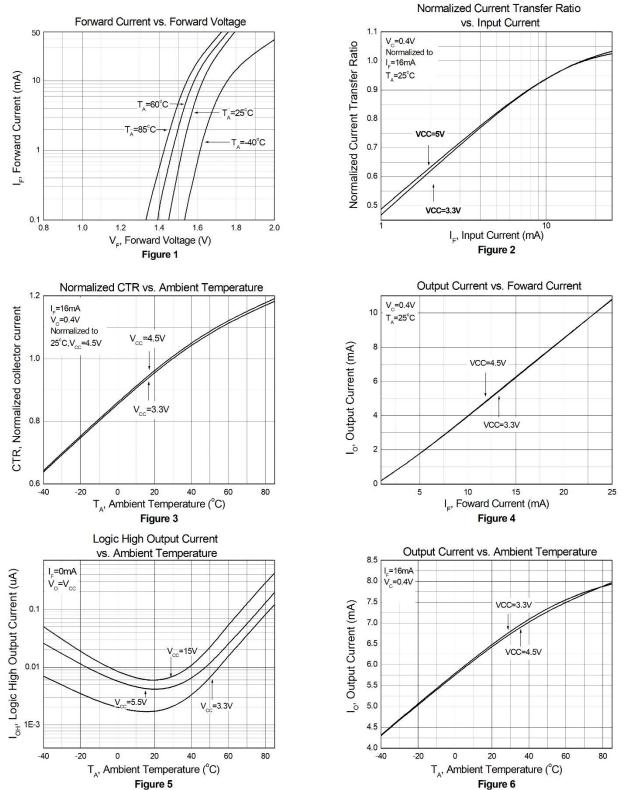
Electrical Characteristics $T_A = 0 - 70^{\circ}$ C (unless otherwise specified). Typical values are measured at $T_A = 25^{\circ}$ C and $V_{cc} = 5V$

Switching Characteristics

Symbol	Parameters		Test Conditions	Min	Тур	Max	Units	Notes
			I⊧=16mA, R∟=1.9KΩ,	-	0.35	0.8		
			T _A =25°C				_	
	Propagation Delay Time I	oaic Hiah	I _F =16mA, R _L =1.9KΩ	-	-	1.0		
TPHL	to Logic Low		IF=16mA, V _{CC} =3.3V		0.4	1	μs	
			R∟=1.9KΩ, T _A =25°C		0.4	I		
			IF=16mA, Vcc=3.3V			4 4		
			R _L =1.9KΩ			1.4		
	Propagation Delay Time Logic Low to Logic High		$I_F=16mA, R_L=1.9K\Omega,$	-	0.3	0.8		
			T _A =25°C				μs	
			I⊧=16mA, R∟=1.9KΩ	-	-	1.0		
TPLH			IF=16mA, Vcc=3.3V			1.5		
			R _L =1.9KΩ, T _A =25°C					
			IF=16mA, V _{CC} =3.3V			2.0		
			R _L =1.9KΩ					
		mon Mode $CTM452$ $I_F = 0mA$, $V_{CM}=10Vp-p$, $R_L=1.9K\Omega$, $T_A=25^{\circ}C$ 5,00	5 000					
			R _L =1.9KΩ, T _A =25°C	5,000	-	-	- V/µs	
СМн	Transient Immunity at	CTM453	$I_F = 0mA$, $V_{CM}=1500Vp-p$,	45.000				
	Logic High		R _L =1.9KΩ, T _A =25°C	15,000	-			
	Common Mode Transient Immunity at	I _F = 16mA , V _{CM} =10Vp-p,	$I_F = 16mA$, $V_{CM}=10Vp-p$,	E 000			— V/μs	
		CTM452	R _L =1.9KΩ, T _A =25°C	5,000	-	-		
CM∟		I _F = 16mA , V _{CM} =1500Vp	I _F = 16mA , V _{CM} =1500Vp-p,	45.000				
	Logic Low CTM4		R _L =1.9KΩ, T _A =25°C	15,000	-			

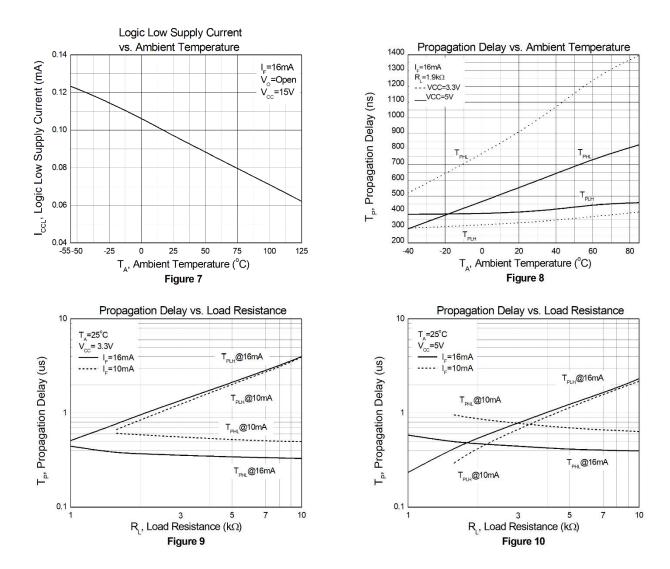






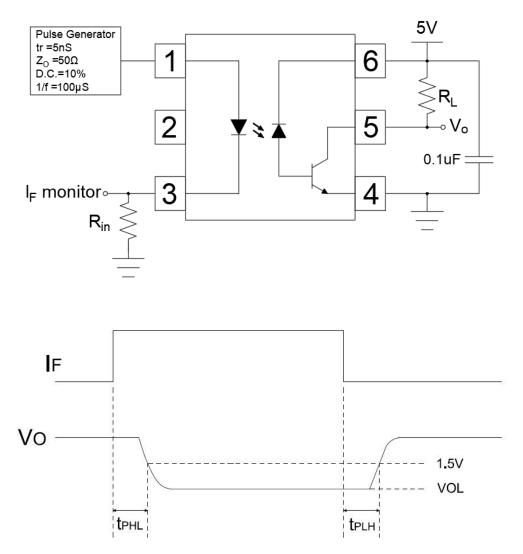


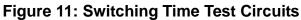
Typical Characteristic Curves T_A = 25°C, unless otherwise specified





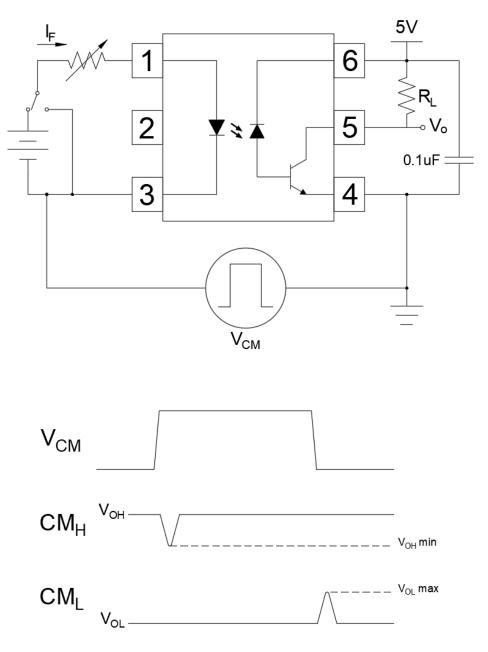
Test Circuits







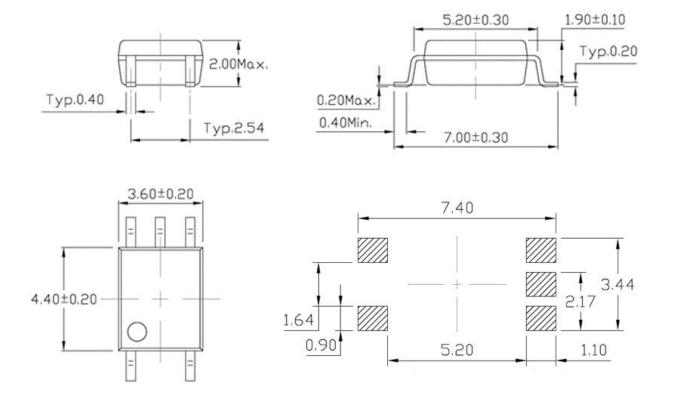
Test Circuits







Package Dimension Dimensions in mm unless otherwise stated



Marking Information



Note:

- CT : Denotes "CT Micro"
- M452 : Product Number
- V : VDE Safety Mark Option
- Y : One Digit Year Code
- WW : Two Digit Work Week
- K : Manufacturing Code



CTM452, CTM453

5 Pin Mini-Flat DMC-Isolator®

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Ordering Information

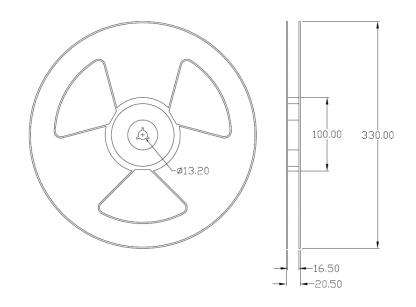
CTM45	5X (V)(Z)
СТ	= Denotes "CT Micro"
M45X	= Product Number (X= 2, or 3)
V	= VDE Safety Mark Option (Blank or V)
_	

Z = Tape and Reel Option (T1 or T2)

Option	Description	Quantity
T1	Surface Mount Lead Forming – With Option 1 Tapping	3000 Units/Reel
T2	Surface Mount Lead Forming – With Option 2 Tapping	3000 Units/Reel

Reel Dimension All dimensions are in mm, unless otherwise stated

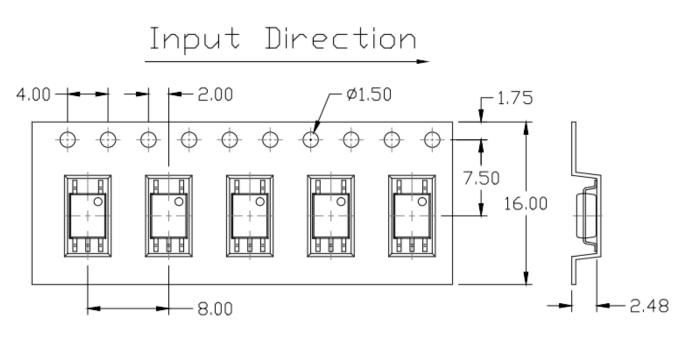
Option T1/T2





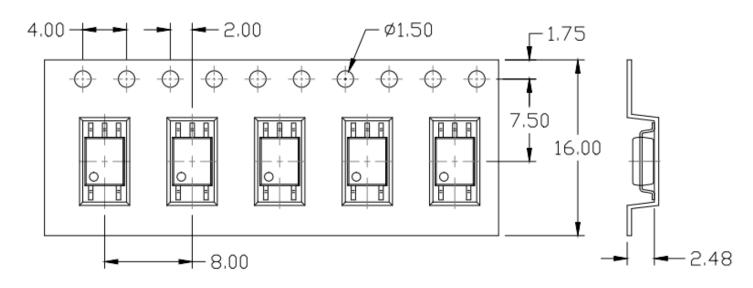
Carrier Tape Specifications Dimensions in mm unless otherwise stated

Option T1



Option T2







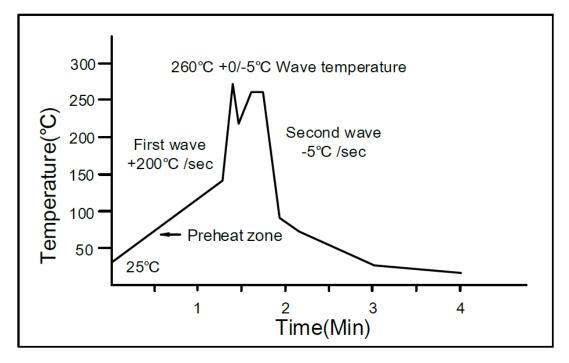
Solderability spec (Follow the JEDEC standard JESD22-B102)

Reflow Soldering: Immersed surface, other than the end of pin as cut-surface, must be covered by solder.

Solder-Bath: More than 95% of the electrode must be covered with solder.

Wave soldering (Follow the JEDEC standard JESD22-A111)

One time soldering is recommended within the condition of temperature. Temperature: 260+0/-5°C. Time: 10 sec. Preheat temperature: 25 to 140°C. Preheat time: 30 to 80 sec.



Iron soldering (Follow the standard MIL-STD 202G, Method 210F)

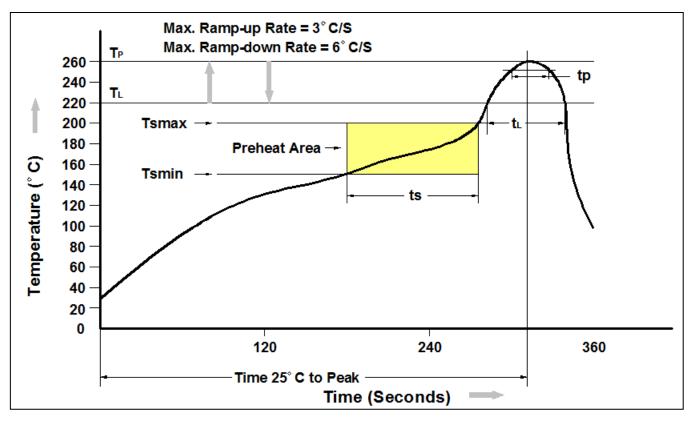
Allow single lead soldering in every single process. One time soldering is recommended. Temperature: 350±10°C Time: 5 sec max.



CTM452, CTM453 5 Pin Mini-Flat DMC-Isolator®

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Reflow Profile (Follow the JEDEC standard J-STD-020)



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t∟ to t⊳)	3°C/second max.
Liquidous Temperature (T∟)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T_P to T_L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



CTM452, CTM453

5 Pin Mini-Flat DMC-Isolator®

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